

10.3.2 Write Transactions

Table 10.4 1.8V Write Timing Parameters

Parameter	Symbol	166 MHz		133 MHz		100 MHz		Unit
		Min	Max	Min	Max	Min	Max	
Read-Write Recovery Time	t_{RWR}	36	–	37.5	–	40	–	ns
Access Time	t_{ACC}	36	–	37.5	–	40	–	ns
Refresh Time	t_{RFH}	36	–	37.5	–	40	–	ns
Chip Select Maximum Low Time – Industrial Temperature	t_{CSM}	–	4.0	–	4.0	–	4.0	μ s
Chip Select Maximum Low Time – Industrial Plus Temperature		–	1.0	–	1.0	–	1.0	μ s

Table 10.5 3.0V Write Timing Parameters

Parameter	Symbol	100 MHz		Unit
		Min	Max	
Read-Write Recovery Time	t_{RWR}	40	–	ns
Access Time	t_{ACC}	40	–	ns
Refresh Time	t_{RFH}	40	–	ns
Chip Select Maximum Low Time – Industrial Temperature	t_{CSM}	–	4.0	μ s
Chip Select Maximum Low Time – Industrial Plus Temperature		–	1.0	μ s

